

Product Summary

V_{DS} (V)	$R_{DS(on),max}$ (mΩ)	I_D (A)
40	1.4@ $V_{GS} = 10V$	190 ⁽¹⁾

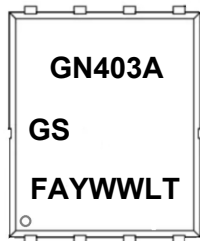
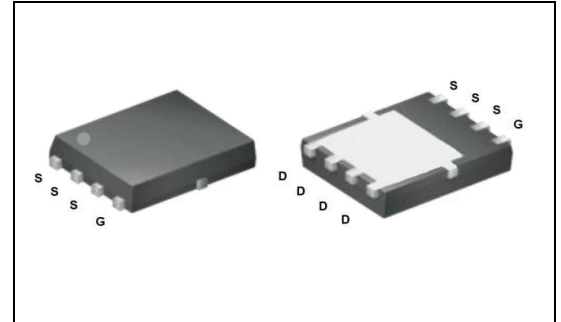
Features

- Low $R_{DS(on)}$ SGT technology
- Low thermal impedance
- Fast switching speed
- 100% avalanche tested

Application

- Power management
- SMPS and general purpose applications
- Uninterruptible Power Supply
- Load Switch

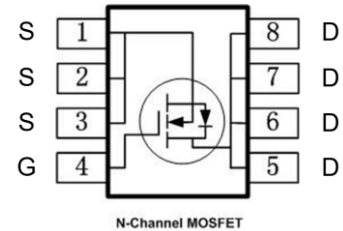
PDFN5060



PDFN5060

NOTE:
 LOGO - GS
 GN403A- Part number
 code F - Fab location code
 A - Assembly location code
 Y - Year code
 WW - Week code
 L&T - Assembly lot code

Equivalent circuit



Absolute maximum rating@25°C

Parameter	Symbol	Limit	Unit
Drain-source voltage	V_{DS}	40	V
Gate-source voltage	V_{GS}	±20	
Continuous drain current	I_D	190	A
Pulsed drain current ⁽²⁾	$I_{D,pulse}$	760	
Avalanche energy, single pulse ⁽³⁾	E_{AS}	677	mJ
Power dissipation	P_D	100	W
Operating junction and storage temperature range	T_J, T_{stg}	-55 to 150	°C

Thermal Characteristic

Parameter	Symbol	Max.	Unit
Thermal resistance, junction-to-case	$R_{\theta JC}$	1.25	°C/W
Thermal resistance, junction-to-ambient ⁽⁴⁾	$R_{\theta JA}$	58	

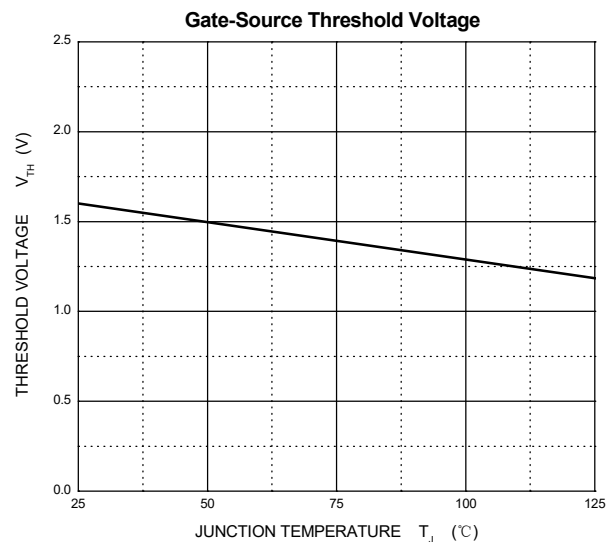
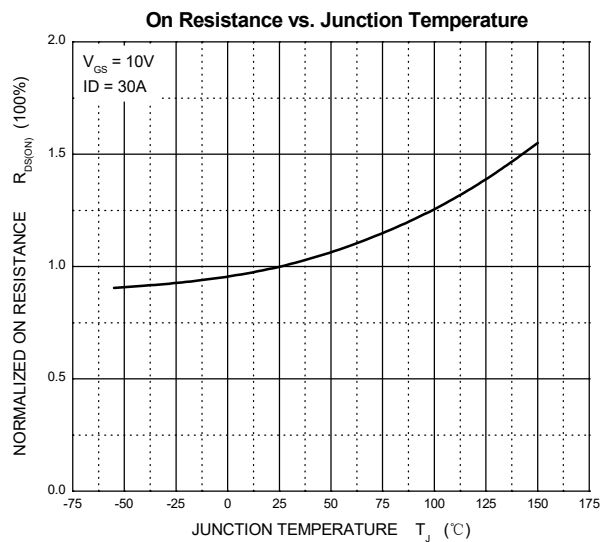
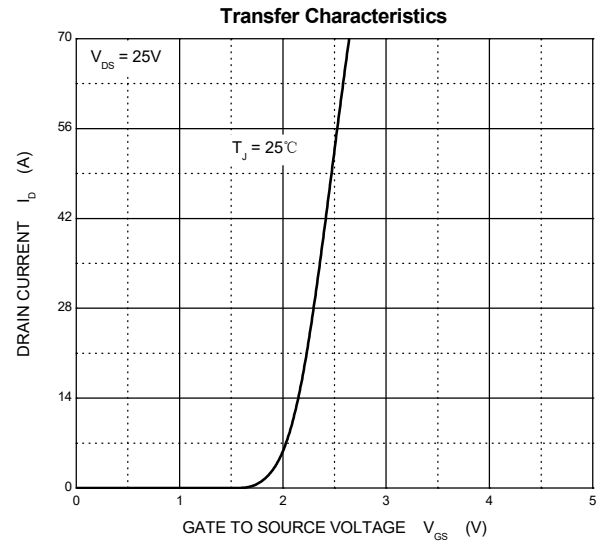
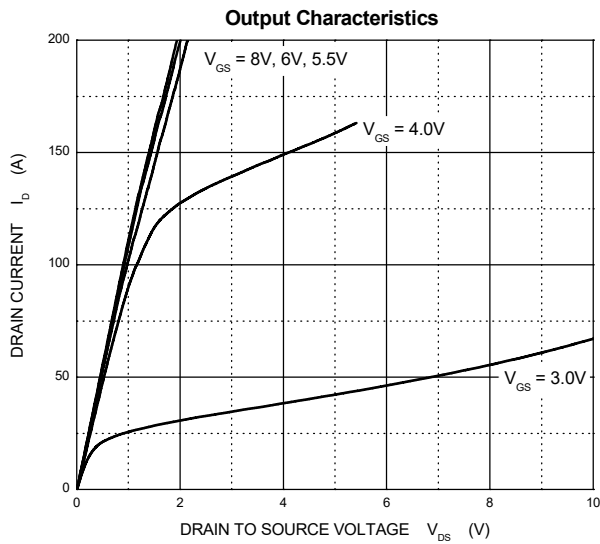
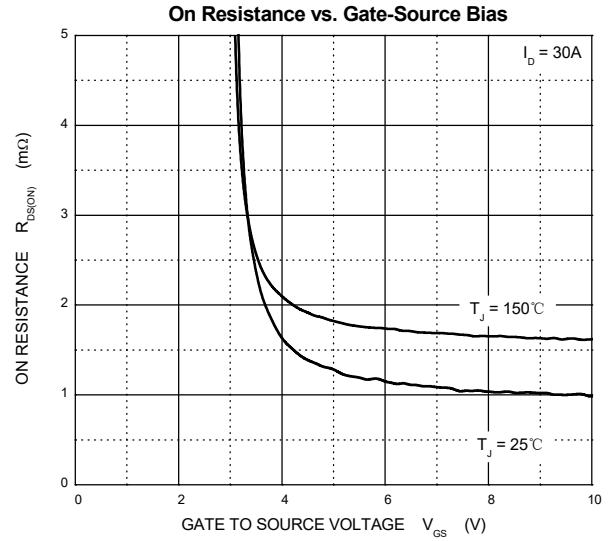
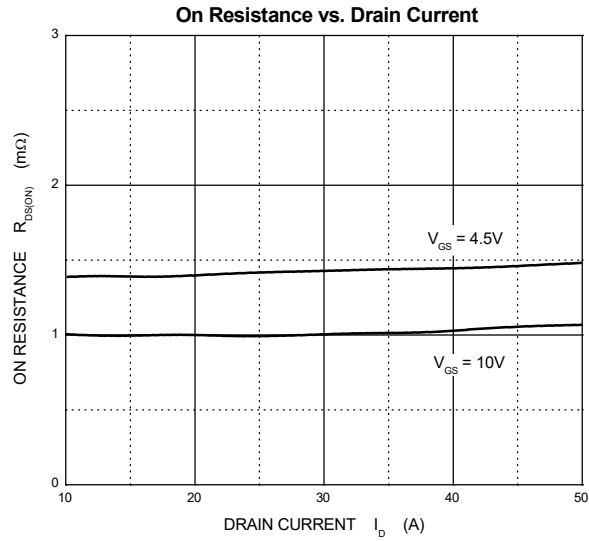
Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Static parameter						
Drain to source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0, I _D = 250 μA	40			V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.2	1.45	2.4	V
Gate-body leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V			±100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V			1	μA
Drain-source on-resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 20 A		1.08	1.4	mΩ
		V _{GS} = 4.5 V, I _D = 20 A		1.3	1.8	mΩ
Forward transconductance ⁽⁵⁾	g _{fs}	V _{DS} = 5 V, I _D = 30 A		54		S
Gate resistance	R _g	f = 1 MHz		2.5		Ω
Dynamic ⁽⁵⁾						
Total gate charge V _{GS} = 10V	Q _g	V _{DS} = 20 V, I _D = 20 A, V _{GS} = 10 V		69		nC
Total gate charge V _{GS} = 6.0V	Q _g			34		
Gate-source charge	Q _{gs}			14.6		
Gate-drain charge	Q _{gd}			14.5		
Turn-on delay time	t _{d(on)}	V _{DS} = 20 V, R _L = 0.4 Ω, V _{GS} = 10 V, R _{GEN} = 2.5 Ω		4.4		ns
Rise time	t _r			19.8		
Turn-off delay time	t _{d(off)}			76		
Fall time	t _f			73.7		
Input capacitance	C _{iss}	V _{DS} = 20 V, V _{GS} = 0 V, f = 100K Hz		5205		pF
Output capacitance	C _{oss}			1755		
Reverse transfer capacitance	C _{rss}			60		
Reverse Diode Characteristics ⁽⁵⁾						
Diode forward voltage	V _{SD}	V _{GS} = 0 V, I _F = 2 A		0.8	1.2	V
Reverse recovery time	t _{rr}	I _F = 20 A, di/dt = 100 A/μs		138		ns
Reverse recovery charge	Q _{rr}			427		nC

Notes

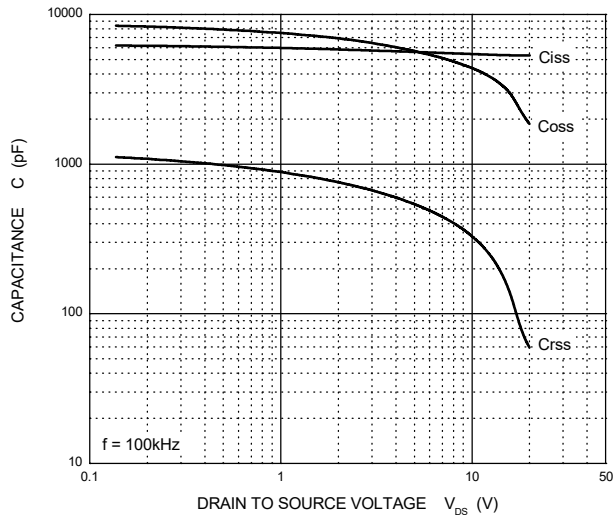
- (1) Limited by maximum junction temperature.
- (2) Pulse width limited by maximum junction temperature.
- (3) V_{DS} = 20 V, V_{GS} = 10 V, L = 0.5 mH.
- (4) Device mounted on FR-4 substrate PC board with 2oz copper in 1inch square cooling area.
- (5) Guaranteed by design, not subject to production testing.

Typical Performance Characteristics

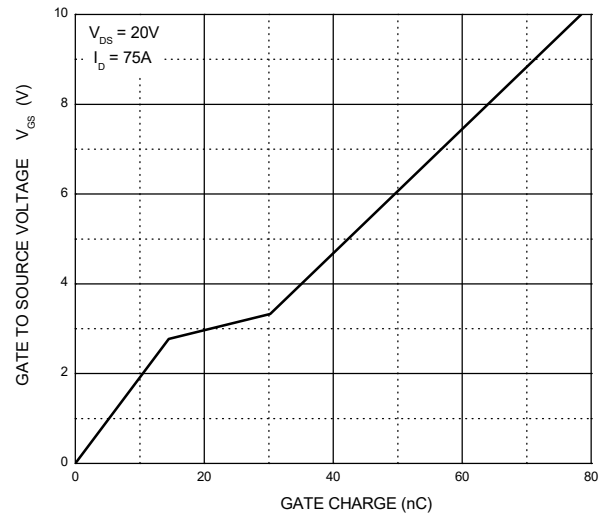


Typical Performance Characteristics

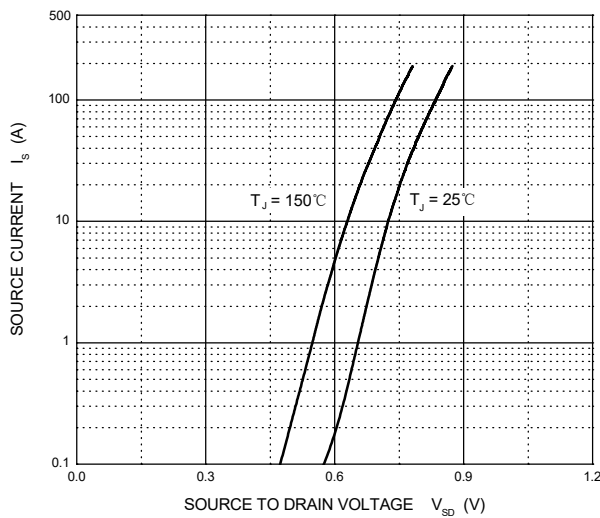
Typical Capacitances



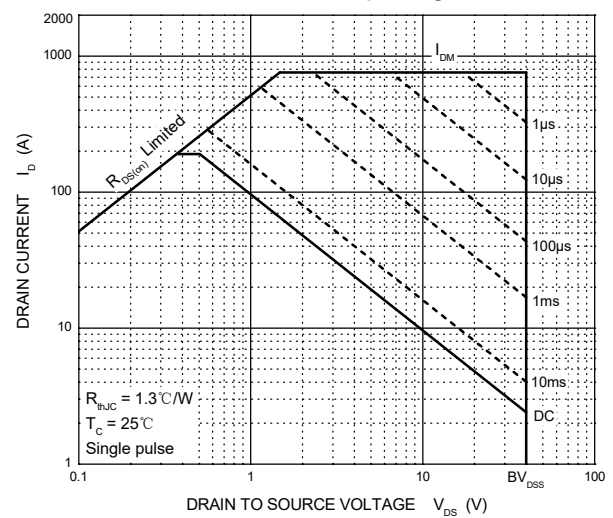
Gate Charge



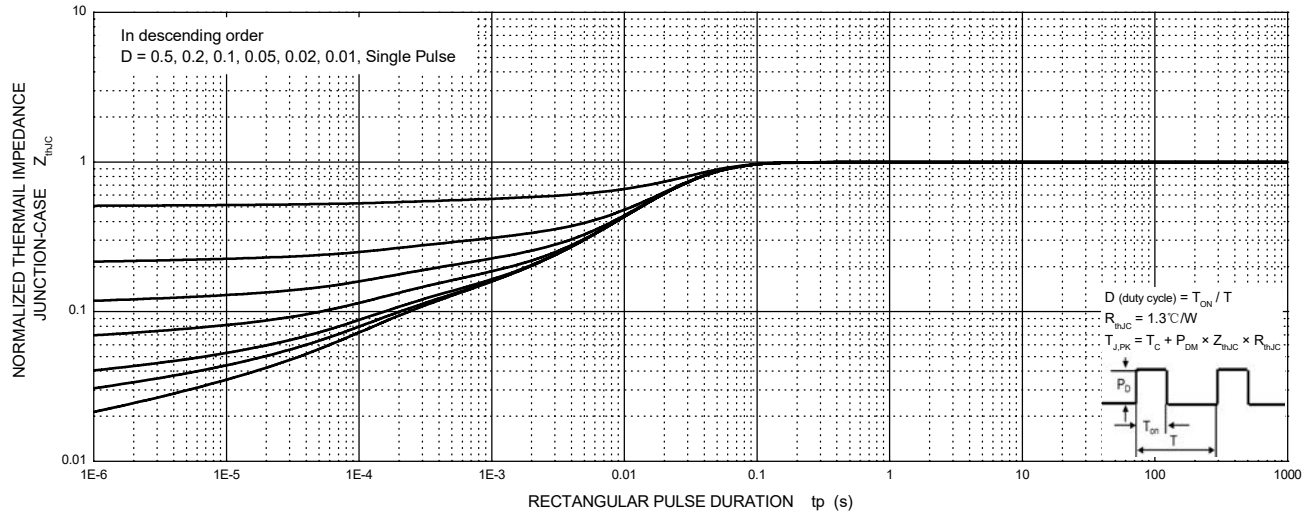
Source-Drain Diode Forward Characteristics

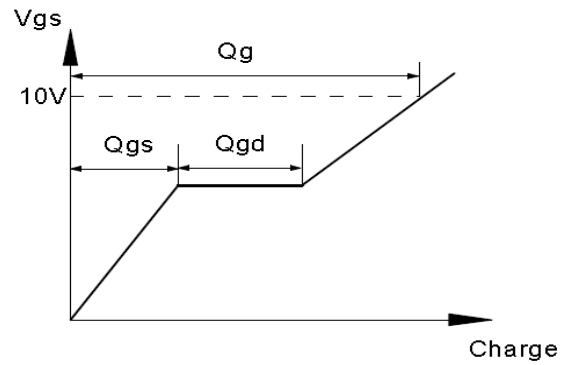
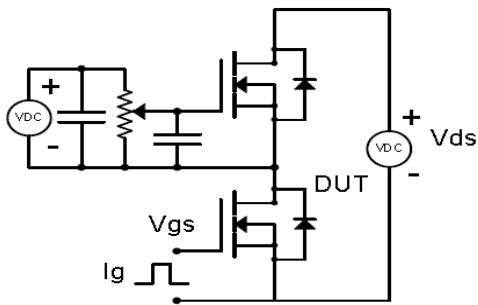
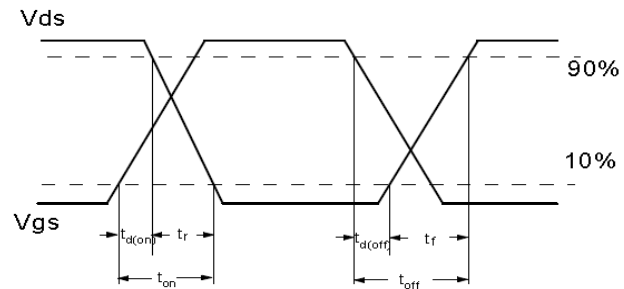
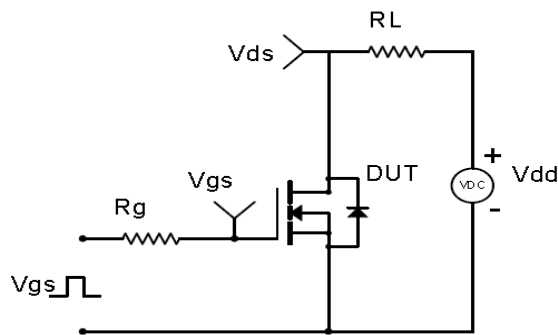
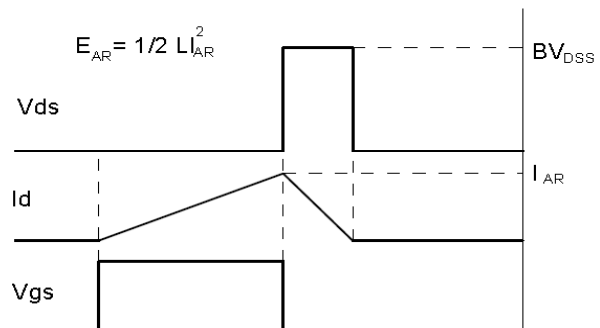
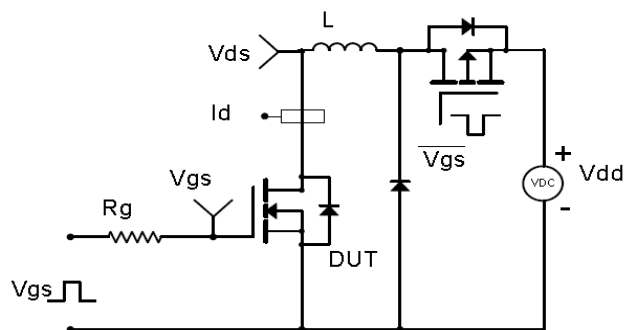
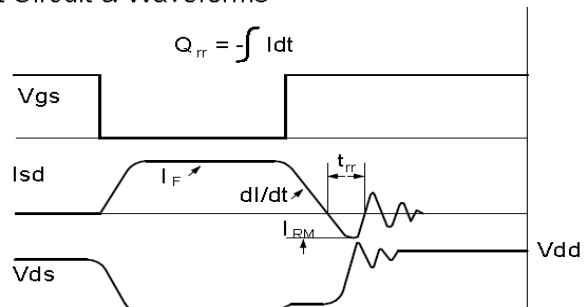
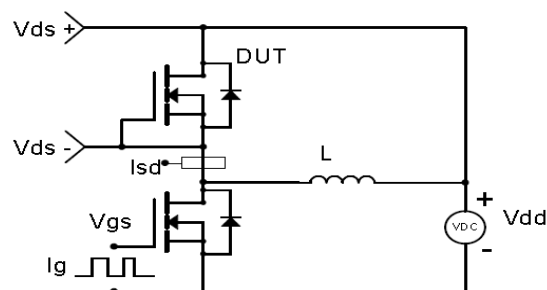


Maximum Safe Operating Area



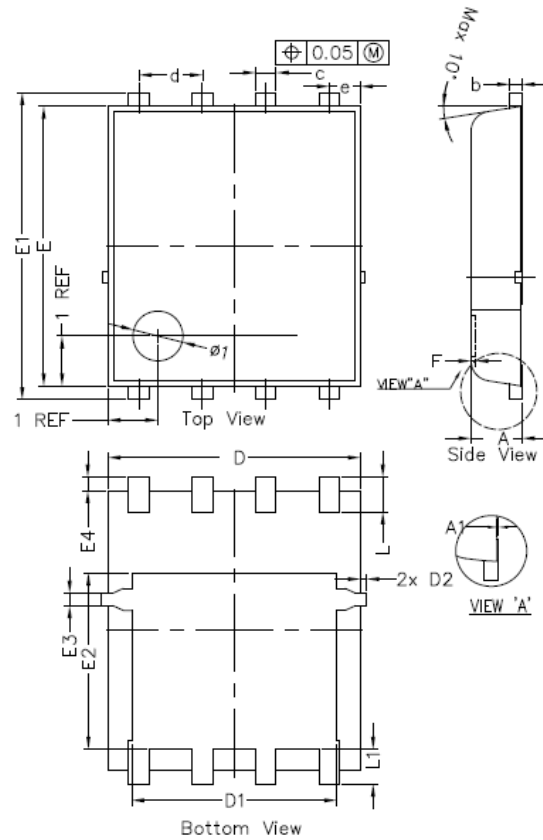
Transient Thermal Impedance, Junction-Case



Test Circuit & Waveform
Gate Charge Test Circuit & Waveform

Resistive Switching Test Circuit & Waveforms

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

Diode Recovery Test Circuit & Waveforms




Outline Drawing PDFN5060



Dim	Millimeters		
	Min	Nom	Max
A	0.900	1.000	1.100
A1	0.000	---	0.050
b	0.246	0.254	0.312
c	0.310	0.410	0.510
d	1.27BSC		
D	4.950	5.050	5.150
D1	4.000	4.100	4.200
D2	---	---	0.125
e	0.62BSC		
E	5.500	5.600	5.700
E1	6.050	6.150	6.250
E2	3.425	3.525	3.625
E3	0.150	0.250	0.350
E4	0.175	0.275	0.375
F	---	---	0.100
L	0.500	0.600	0.700
L1	0.600	0.700	0.800

Important Notice

The information given in this document shall be for illustrative purposes only and shall in no event be regarded as a guarantee of conditions or characteristics. Gostone reserves the right to change any information herein. With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Gostone or its affiliates hereby make no representation or warranty of any kind, expressed or implied, as to any information provided hereunder, including without limitation as to the accuracy, completeness or non-infringement of intellectual property rights of any third party, and they assume no liability for the consequences of use of such information. In addition, any information given in this document is subject to customer's compliance with its obligations stated herein and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Gostone in customer's applications. The information contained herein is exclusively intended for technically trained staff. No license is granted by implication under any patent right, copyright, mask work right, or other intellectual property right. It is customer's sole responsibility to evaluate the suitability of the product for the intended application and the completeness of the product information given herein with respect to such application. In no event shall Gostone or its affiliates be liable to any party for any direct, indirect, special, punitive, incidental or consequential damages of any nature whatsoever, including but not limited to loss of profits and loss of goodwill, whether or not such damages are based on tort or negligence, warranty, breach of contract or any other legal theory. In addition, any recipient of this document and the relevant products samples may not alter, decompile, disassemble, reverse engineer, or otherwise modify any information/samples received hereunder. Any intellectual property rights arising from the reverse engineering of Gostone's products shall belong to Gostone.